

KSD526 NPN Epitaxial Silicon Transistor

Power Amplifier Applications

· Complement to KSB596



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings * $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	80	V
V _{CEO}	Collector-Emitter Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	4	Α
I _B	Base Current	0.4	Α
P _C	Collector Dissipation (T _C =25°C)	30	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55~150	°C

 $^{^{\}star}$ These ratings are limiting values above which the serviceability of any semiconductor device may by impaired.

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	MIN	MAX	MAX	Units
I _{CBO}	Collector Cut-off Current	V _{CB} = 80V, I _E = 0			30	μА
I _{EBO}	Emitter Cut-off Current	V _{EB} = 5V, I _C = 0			100	μА
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 50mA, I _B = 0	80			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 10mA, I _C = 0	5			V
hfe	DC Current Gain	$V_{CE} = 5V, I_{C} = 0.5A$ $V_{CE} = 5V, I_{C} = 3A$	40 15	50	240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 3A, I_B = 0.3A$		0.45	1.5	V
V _{BE(on)}	Base-Emitter On Voltage	$V_{CE} = 5V, I_{C} = 3A$		1	1.5	V
f⊤	Current Gain - Bandwidth Product	$V_{CE} = 5V, I_{C} = 0.5A$	3	8		MHz
Ccb	Collector Output Capacitance	V _{CB} = 10V, I _E = 0, f = 1MHz		90		pF

h_{FE} Classification

Classification	R	0	Υ
h _{FE}	40~80	70~140	120~240

Typical Characteristics

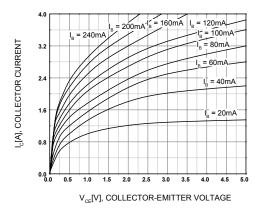


Figure 1. Static Characteristic

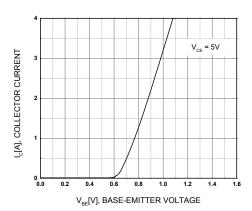


Figure 3. Base-Emitter On Voltage

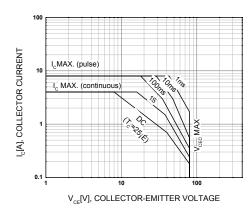


Figure 5. Safe Operating Area

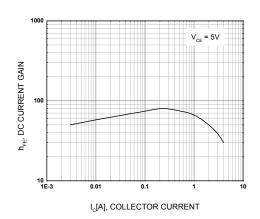


Figure 2. DC current Gain

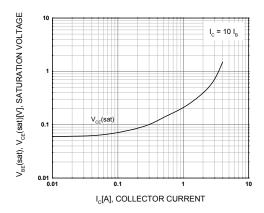


Figure 4. Collector-Emitter Saturation Voltage

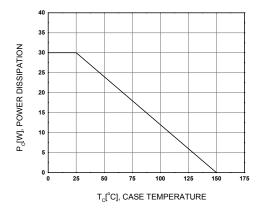
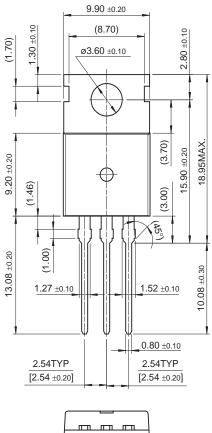


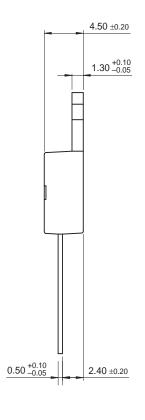
Figure 6. Power Derating

KSD526 Rev. A1

Package Dimensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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